

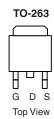
# N-Channel 100-V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
100	0.024 at V <sub>GS</sub> = 10 V	47		
	0.027 at V <sub>GS</sub> = 4.5 V	44		

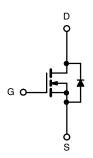
### **FEATURES**

- TrenchFET® Power MOSFET
- 175 °C Maximum Junction Temperature
- 100 % R<sub>g</sub> Tested





Ordering Information: SUM47N10-24L-E3 (Lead (Pb)-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A =$	= 25 °C, unless othe	rwise noted			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V <sub>DS</sub>	100	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20	_ V	
Oastings Dain Oassat (T., 475 00)h	T <sub>C</sub> = 25 °C	,	47		
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>b</sup>	T <sub>C</sub> = 125 °C	l <sub>D</sub>	27		
Pulsed Drain Current		I <sub>DM</sub>	70	A	
Continuous Source Current (Diode Conduction)		I <sub>S</sub>	47		
Single Pulse Avalanche Current		I <sub>AS</sub>	40		
Single Pulse Avalanche Energy (Duty Cycle ≤ 1 %)	L = 0.1 mH	E <sub>AS</sub>	80	mJ	
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	PD	136 <sup>b</sup>	w	
Maximum Fower Dissipation	T <sub>A</sub> = 25 °C	7 'B [	3.75 <sup>a</sup>		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Unit	
Junction-to-Ambient	PCB Mount	R <sub>thJA</sub>	40		
Junction-to-Ambient	Free Air	' 'thJA	62.5	°C/W	
Junction-to-Case		R <sub>thJC</sub>	1.1		

### Notes:

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. See SOA curve for voltage derating.

## SUM47N10-24L

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Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit	
Static	•			1			
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100			V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V			1		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			50	μΑ	
-		V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			250		
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	70			Α	
Drain-Source On-State Resistance <sup>b</sup>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A		0.019	0.024	Ω	
	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A, T <sub>J</sub> = 125 °C			0.048		
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A, T <sub>J</sub> = 175 °C			0.060		
		$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.021	0.027		
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 40 A		70		S	
Dynamic <sup>a</sup>							
Input Capacitance	C <sub>iss</sub>			2400		pF	
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, F = 1 MHz		290			
Reverse Transfer Capacitance	C <sub>rss</sub>			120			
Total Gate Charge <sup>c</sup>	Qg			40	60		
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 40 \text{ A}$		11		nC	
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			9			
Gate Resistance	R <sub>g</sub>	f = 1 MHz	1	2.2	3.5	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			8	13		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = 50 V, $R_L$ = 1.25 $\Omega$ $I_D$ $\cong$ 47 A, $V_{GEN}$ = 10 V, $R_g$ = 2.5 $\Omega$		40	60	ns	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			15	25		
Fall Time <sup>c</sup>	t <sub>f</sub>			80	120		
Source-Drain Diode Ratings and Cha	racteristics T	<sub>C</sub> = 25 °C					
Pulsed Current	I <sub>SM</sub>				70	Α	
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V}$		1.0	1.5	V	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 47 A, di/dt = 100 A/μs		75	120	ns	

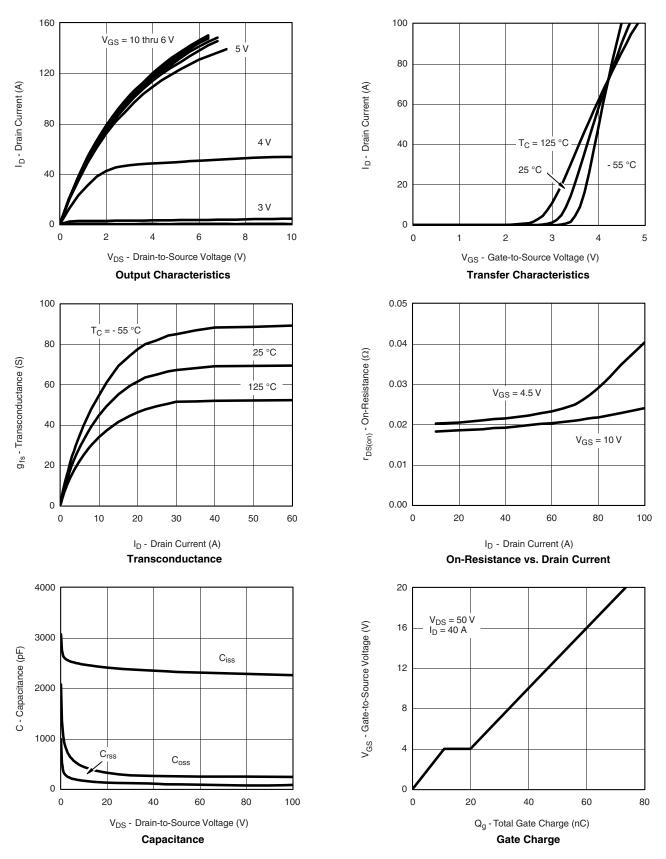
### Notes:

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



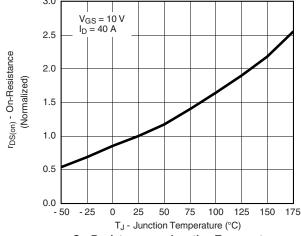
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



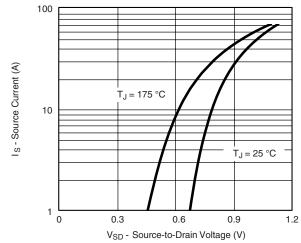
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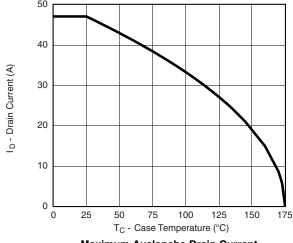


On-Resistance vs. Junction Temperature

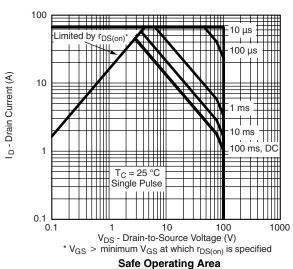


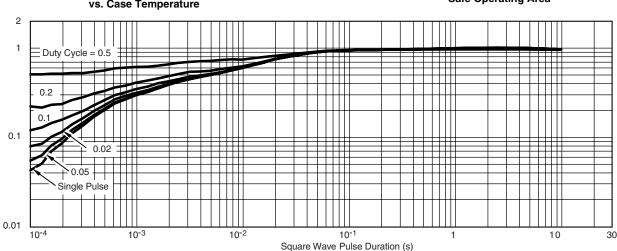
Source-Drain Diode Forward Voltage

### THERMAL RATINGS



Maximum Avalanche Drain Current vs. Case Temperature





Normalized Thermal Transient Impedance, Junction-to-Case

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Normalized Effective Transient Thermal Impedance



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